

LIST OF PUBLICATIONS, BY SUBJECT*
ALEX ZUNGER

Table of Contents	Page
(A) DENSITY FUNCTIONAL THEORY.....	3
(B) PSEUDOPOTENTIAL THEORY.....	3
(C) MANY-ELECTRON AND EXCHANGE-CORRELATION EFFECTS.....	4
(D) QUANTUM STRUCTURAL DIAGRAMS AND ORBITAL RADII.....	6
(E) ORDER-DISORDER TRANSITIONS.....	7
(F) PHONONS AND EXCITONS.....	10
(G) QUANTUM NANOSTRUCTURES: DOTS, FILMS, WIRES.....	13
(H) SUPERLATTICES AND QUANTUM WELLS.....	21
(I) PHYSICS OF 2D EPITAXIAL STABILITY.....	25
(J) ELECTRON DENSITY DISTRIBUTION IN SOLIDS.....	26
(K) DEVELOPMENT OF THEORETICAL AND COMPUTATIONAL TECHNIQUES: Total energy, Eigenvalues and forces in solids.....	27
(L) DEVELOPMENT OF THEORETICAL AND COMPUTATIONAL TECHNIQUES: Statistical Mechanics of Alloys.....	28
(M) DEVELOPMENT OF THEORETICAL AND COMPUTATIONAL TECHNIQUES: Electronic Structure of Random Networks.....	31
(N) DEVELOPMENT OF THEORETICAL AND COMPUTATIONAL TECHNIQUES: Green's Functions For Defects In Solids.....	32
(O) ELECTRONIC STRUCTURE OF SPECIFIC BULK SOLIDS.....	33
Binary Semiconductors and Insulators.....	33
Ternary Chalcopyrites & Photovoltaic Materials	36
Metals and Intermetallics	40
Layered Transition Metal Compounds	44
Filled Tetrahedral Structures.....	44
Pseudo One Dimensional Chains	45
Two Dimensional and Graphitic Structures	45

Magnetic Semiconductors	46
Molecular Solids	48
Nitrides and the Zincblende/Wurtzite System.....	49
Oxides	51
Antimonides	52
Predicting New Materials	53
(P) ELECTRONIC STRUCTURE OF SURFACES & INTERFACES.....	56
Clean Semiconductor Surfaces; Surface Steps	56
Metal-Semiconductor Interfaces and Schottky Barriers	57
Semiconductor-Semiconductor Heterojunction Band Offsets	57
(Q) ELECTRONIC STRUCTURE OF DEFECTS AND IMPURITIES.....	59
Main Group Defects & Impurities in Semiconductors	59
Transition Metal Impurities in Semiconductors.....	62
Impurity Magnetism.....	65
(R) ELECTRONIC STRUCTURE OF ALLOYS.....	66
Density of States in Transition Metal Alloys.....	66
Optical Properties & Bowing in Semiconductor Alloys.....	67
Short Range Order	72
Atomic-Scale Structure and Relaxation in Alloys	74
Spontaneous Ordering in Semiconductor Alloys.....	76
(S) STATISTICAL MECHANICS AND THERMODYNAMICS OF ALLOYS.....	81
Transition Metal Alloys	81
Isovalent Semiconductor Alloys	86
Ternary and Non-Isovalent Semiconductor Alloys	89
Structural Stability and Interfacial Roughness Of Superlattices	90
(T) HIGH PRESSURE EFFECTS.....	91
(U) THEORY OF DOPING.....	93

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